

BIDIRECTIONAL THYRISTOR OVERVOLTAGE PROTECTORS



TISP4500H3BJ Overvoltage Protector

Non-Conductive During K.20/21/45 Power Contact Test

- Off-State Voltage >245 V rms
- For Controlled Environment 0 °C to 70 °C

Ion-Implanted Breakdown Region

Precise and Stable Voltage

Low Voltage Overshoot under Surge

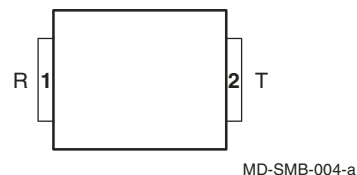
Device	V_{DRM}	$V_{(BO)}$
	V @ 0 °C	V @ 70 °C
TISP4500H3BJ	350	500

Rated for International Surge Wave Shapes

Wave Shape	Standard	I_{PPSM} A
2/10	GR-1089-CORE	500
10/250	GR-1089-CORE	230
10/700	ITU-T K.20/21/45	200
10/1000	GR-1089-CORE	100

 UL Recognized Component

SMBJ Package (Top View)



Device Symbol



SD-TISP4xxx-001-a

Description

This device is designed to limit overvoltages on the telephone line to ± 500 V over the temperature range. The minimum off-state voltage of ± 350 V allows a.c. power contact voltages of up to 245 V rms to occur without clipping. The combination of these two voltages gives protection for components having ratings of 500 V or above and ensures the protector is non-conducting for the ITU-T recommendations K.20/21/45 230 V rms power cross test condition (test number 2.3.1).

The protector consists of a symmetrical voltage-triggered bidirectional thyristor. Overvoltages are initially clipped by breakdown clamping until the voltage rises to the breakover level, which causes the device to crowbar into a low-voltage on state. This low-voltage on state causes the current resulting from the overvoltage to be safely diverted through the device. The high crowbar holding current helps prevent d.c. latchup as the diverted current subsides.

How To Order

Device	Package	Carrier	Order As	Marking Code	Std. Qty.
TISP4500H3BJ	SMB (DO-214AA)	Embossed Tape Reeled	TISP4500H3BJR-S	4500H3	3000

TISP4500H3BJ Overvoltage Protector

BOURNS®

Absolute Maximum Ratings, $0\text{ }^{\circ}\text{C} \leq T_A \leq 70\text{ }^{\circ}\text{C}$ (Unless Otherwise Noted)

Rating	Symbol	Value	Unit
Repetitive peak off-state voltage	V_{DRM}	± 350	V
Non-repetitive peak on-state pulse current (see Notes 1 and 2) 2/10 (Telcordia GR-1089-CORE, 2/10 μs voltage wave shape) 10/250 (Telcordia GR-1089-CORE, 10/250 μs voltage wave shape) 10/700 (ITU-T K.20/21/45, 5/310 μs current wave shape) 10/1000 (Telcordia GR-1089-CORE, 10/1000 μs voltage wave shape)	I_{PPSM}	$T_A = 25\text{ }^{\circ}\text{C}$ 500 $T_A = 25\text{ }^{\circ}\text{C}$ 230 200 $T_A = 25\text{ }^{\circ}\text{C}$ 100	A
Non-repetitive peak on-state current (see Notes 1, 2 and 3) 50 Hz, 20 ms (1 cycle) 50 Hz, 1000 s	I_{TSM}	± 55 ± 2.0	A
Junction temperature	T_J	-40 to +150	$^{\circ}\text{C}$
Storage temperature range	T_{stg}	-65 to +150	$^{\circ}\text{C}$

- NOTES: 1. Initially the device must be in thermal equilibrium.
2. The surge may be repeated after the device returns to its initial conditions.
3. EIA/JESD51-2 environment and EIA/JESD51-3 PCB with standard footprint dimensions connected with 5 A rated printed wiring track widths.

Electrical Characteristics, $0\text{ }^{\circ}\text{C} \leq T_A \leq 70\text{ }^{\circ}\text{C}$ (Unless Otherwise Noted)

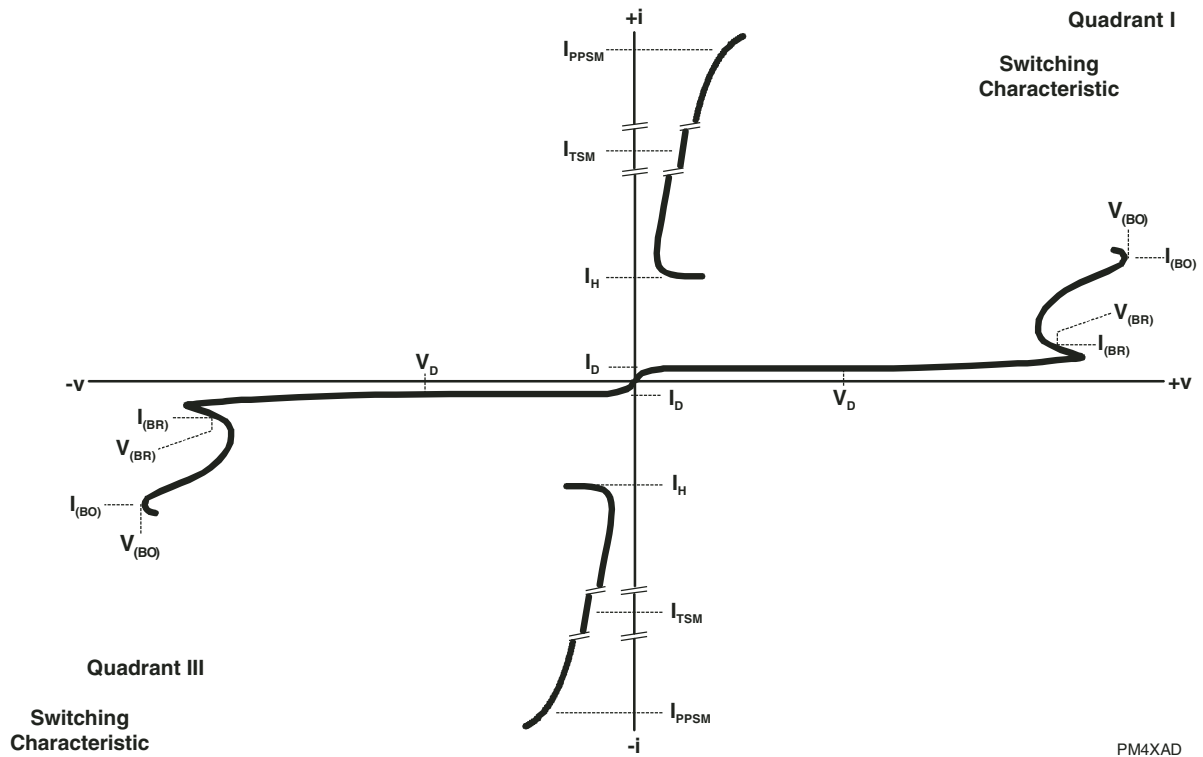
Parameter	Test Conditions	Min	Typ	Max	Unit
I_{DRM} Repetitive peak off-state current	$V_D = V_{\text{DRM}}$ $T_A = 25\text{ }^{\circ}\text{C}$ $T_A = 70\text{ }^{\circ}\text{C}$			± 5 ± 10	μA
$V_{(\text{BO})}$ Breakover voltage	$dv/dt = \pm 250\text{ V/ms}$, $R_{\text{SOURCE}} = 300\ \Omega$			± 500	V
$V_{(\text{BO})}$ Impulse breakover voltage	ITU-T recommendation K.44 (02/2000) Figure A.3-1/K.44 10/700 impulse generator Charge Voltage = $\pm 4\text{ kV}$			± 500	V
$I_{(\text{BO})}$ Breakover current	$dv/dt = \pm 250\text{ V/ms}$, $R_{\text{SOURCE}} = 300\ \Omega$			± 0.6	A
I_H Holding current	$I_T = \pm 5\text{ A}$, $di/dt = -/+30\text{ mA/ms}$	± 0.15			A
I_D Off-state current	$V_D = \pm 50\text{ V}$ $T_A = 70\text{ }^{\circ}\text{C}$			± 10	μA
C_{off} Off-state capacitance	$f = 1\text{ MHz}$, $V_d = 1\text{ V rms}$, $V_D = 0$ $f = 1\text{ MHz}$, $V_d = 1\text{ V rms}$, $V_D = -1\text{ V}$ $f = 1\text{ MHz}$, $V_d = 1\text{ V rms}$, $V_D = -2\text{ V}$ $f = 1\text{ MHz}$, $V_d = 1\text{ V rms}$, $V_D = -50\text{ V}$			84 67 62 31	pF

Thermal Characteristics

Parameter	Test Conditions	Min	Typ	Max	Unit
$R_{\theta\text{JA}}$ Junction to free air thermal resistance	EIA/JESD51-3 PCB, $I_T = I_{\text{TSM}(1000)}$, $T_A = 25\text{ }^{\circ}\text{C}$, (see Note 5)			113	$^{\circ}\text{C/W}$
	265 mm x 210 mm populated line card, 4-layer PCB, $I_T = I_{\text{TSM}(1000)}$, $T_A = 25\text{ }^{\circ}\text{C}$		50		

NOTE 5: EIA/JESD51-2 environment and PCB has standard footprint dimensions connected with 5 A rated printed wiring track widths.

Parameter Measurement Information



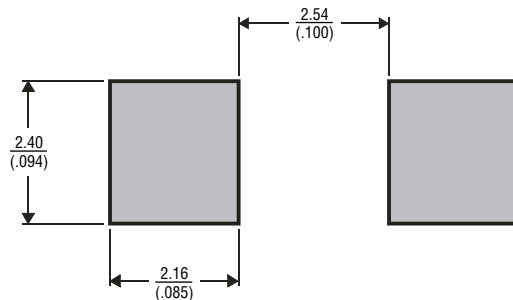
PM4XAD

Figure 1. Voltage-current Characteristic for T and R Terminals
All Measurements are Referenced to the R Terminal

MECHANICAL DATA

Recommended Printed Wiring Land Pattern Dimensions

SMB Land Pattern



DIMENSIONS ARE: $\frac{\text{MM}}{\text{(INCHES)}}$

MDXXBIB

Device Symbolization Code

Devices will be coded as below. As the device parameters are symmetrical, terminal 1 is not identified.

Device	Symbolization Code
TISP4500H3BJ	4500H3

Компания «Life Electronics» занимается поставками электронных компонентов импортного и отечественного производства от производителей и со складов крупных дистрибьюторов Европы, Америки и Азии.

С конца 2013 года компания активно расширяет линейку поставок компонентов по направлению коаксиальный кабель, кварцевые генераторы и конденсаторы (керамические, пленочные, электролитические), за счёт заключения дистрибьюторских договоров

Мы предлагаем:

- Конкурентоспособные цены и скидки постоянным клиентам.
- Специальные условия для постоянных клиентов.
- Подбор аналогов.
- Поставку компонентов в любых объемах, удовлетворяющих вашим потребностям.
- Приемлемые сроки поставки, возможна ускоренная поставка.
- Доставку товара в любую точку России и стран СНГ.
- Комплексную поставку.
- Работу по проектам и поставку образцов.
- Формирование склада под заказчика.
- Сертификаты соответствия на поставляемую продукцию (по желанию клиента).
- Тестирование поставляемой продукции.
- Поставку компонентов, требующих военную и космическую приемку.
- Входной контроль качества.
- Наличие сертификата ISO.

В составе нашей компании организован Конструкторский отдел, призванный помогать разработчикам, и инженерам.

Конструкторский отдел помогает осуществить:

- Регистрацию проекта у производителя компонентов.
- Техническую поддержку проекта.
- Защиту от снятия компонента с производства.
- Оценку стоимости проекта по компонентам.
- Изготовление тестовой платы монтаж и пусконаладочные работы.



Тел: +7 (812) 336 43 04 (многоканальный)

Email: org@lifeelectronics.ru